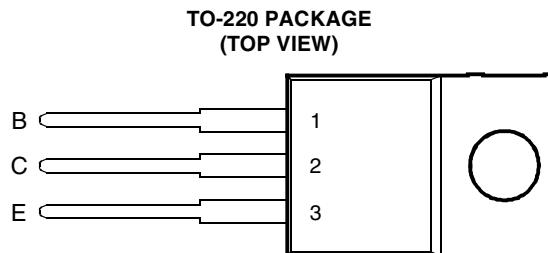


- Designed for Complementary Use with BDT61, BDT61A, BDT61B and BDT61C
- 50 W at 25°C Case Temperature
- 4 A Continuous Collector Current
- Minimum  $h_{FE}$  of 750 at 1.5V, 3 A



Pin 2 is in electrical contact with the mounting base.

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### absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage ( $I_E = 0$ )	BDT60 BDT60A BDT60B BDT60C	$V_{CBO}$	-60 -80 -100 -120	V
Collector-emitter voltage ( $I_B = 0$ )	BDT60 BDT60A BDT60B BDT60C	$V_{CEO}$	-60 -80 -100 -120	V
Emitter-base voltage		$V_{EBO}$	-5	V
Continuous collector current		$I_C$	-4	A
Continuous base current		$I_B$	-0.1	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 1)		$P_{tot}$	50	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 2)		$P_{tot}$	2	W
Operating junction temperature range		$T_j$	-65 to +150	°C
Storage temperature range		$T_{stg}$	-65 to +150	°C
Operating free-air temperature range		$T_A$	-65 to +150	°C

NOTES: 1. Derate linearly to 150°C case temperature at the rate of 0.4 W/°C.  
2. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

### PRODUCT INFORMATION

**electrical characteristics at 25°C case temperature (unless otherwise noted)**

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$ Collector-emitter breakdown voltage	$I_C = -30 \text{ mA}$	$I_B = 0$	(see Note 3)	BDT60 BDT60A BDT60B BDT60C	-60 -80 -100 -120		V
$I_{CEO}$ Collector-emitter cut-off current	$V_{CE} = -30 \text{ V}$	$I_B = 0$		BDT60		-0.5	
	$V_{CE} = -40 \text{ V}$	$I_B = 0$		BDT60A		-0.5	
	$V_{CE} = -50 \text{ V}$	$I_B = 0$		BDT60B		-0.5	
	$V_{CE} = -60 \text{ V}$	$I_B = 0$		BDT60C		-0.5	
$I_{CBO}$ Collector cut-off current	$V_{CB} = -60 \text{ V}$	$I_E = 0$		BDT60		-0.2	
	$V_{CB} = -80 \text{ V}$	$I_E = 0$		BDT60A		-0.2	
	$V_{CB} = -100 \text{ V}$	$I_E = 0$		BDT60B		-0.2	
	$V_{CB} = -120 \text{ V}$	$I_E = 0$		BDT60C		-0.2	
	$V_{CB} = -30 \text{ V}$	$I_E = 0$	$T_C = 150^\circ\text{C}$	BDT60		-2.0	
	$V_{CB} = -40 \text{ V}$	$I_E = 0$	$T_C = 150^\circ\text{C}$	BDT60A		-2.0	
	$V_{CB} = -50 \text{ V}$	$I_E = 0$	$T_C = 150^\circ\text{C}$	BDT60B		-2.0	
	$V_{CB} = -60 \text{ V}$	$I_E = 0$	$T_C = 150^\circ\text{C}$	BDT60C		-2.0	
$I_{EBO}$ Emitter cut-off current	$V_{EB} = -5 \text{ V}$	$I_C = 0$				-5	mA
$h_{FE}$ Forward current transfer ratio	$V_{CE} = -3 \text{ V}$	$I_C = -1.5 \text{ A}$	(see Notes 3 and 4)	750			
$V_{CE(\text{sat})}$ Collector-emitter saturation voltage	$I_B = -6 \text{ mA}$	$I_C = -1.5 \text{ A}$	(see Notes 3 and 4)			-2.5	V
$V_{BE(\text{on})}$ Base-emitter voltage	$V_{CE} = -3 \text{ V}$	$I_C = -1.5 \text{ A}$	(see Notes 3 and 4)			-2.5	V
$V_{EC}$ Parallel diode forward voltage	$I_E = -1.5 \text{ A}$	$I_B = 0$				-2.0	V

NOTES: 3. These parameters must be measured using pulse techniques,  $t_p = 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .

4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

**thermal characteristics**

PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$ Junction to case thermal resistance			2.5	°C/W
$R_{\theta JA}$ Junction to free air thermal resistance			62.5	°C/W

**resistive-load-switching characteristics at 25°C case temperature**

PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
$t_{on}$ Turn-on time	$I_C = -2 \text{ A}$	$I_{B(on)} = -8 \text{ mA}$	$I_{B(off)} = 8 \text{ mA}$		1		μs
$t_{off}$ Turn-off time	$V_{BE(off)} = 5 \text{ V}$	$R_L = 20 \Omega$	$t_p = 20 \mu\text{s}, dc \leq 2\%$		4.5		μs

† Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

**PRODUCT INFORMATION**

## TYPICAL CHARACTERISTICS

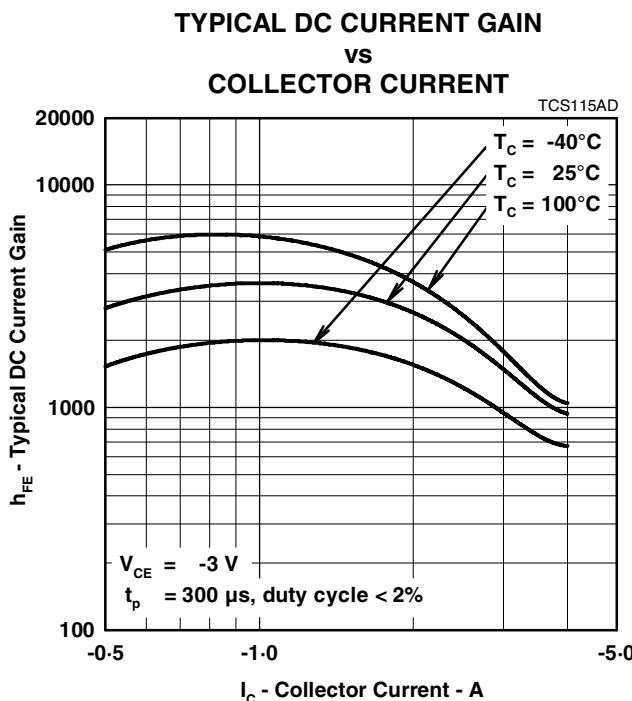


Figure 1.

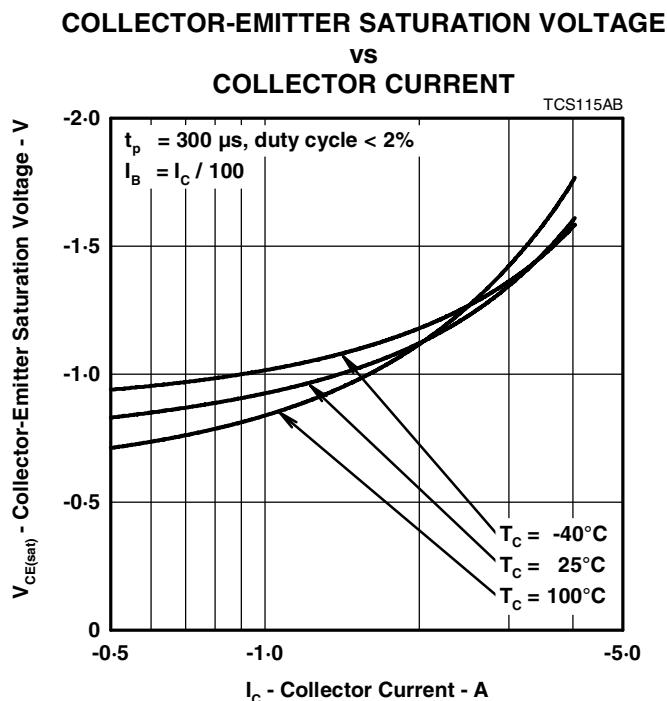


Figure 2.

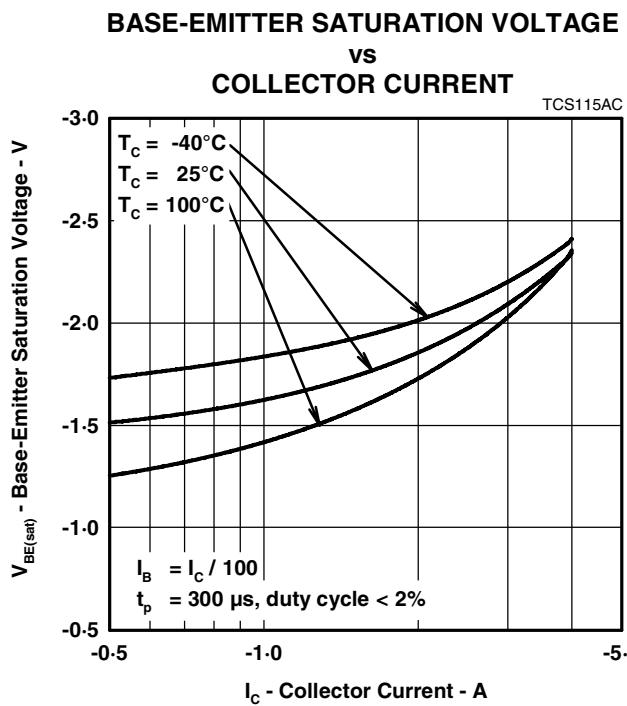


Figure 3.

**PRODUCT INFORMATION**

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### MAXIMUM SAFE OPERATING REGIONS

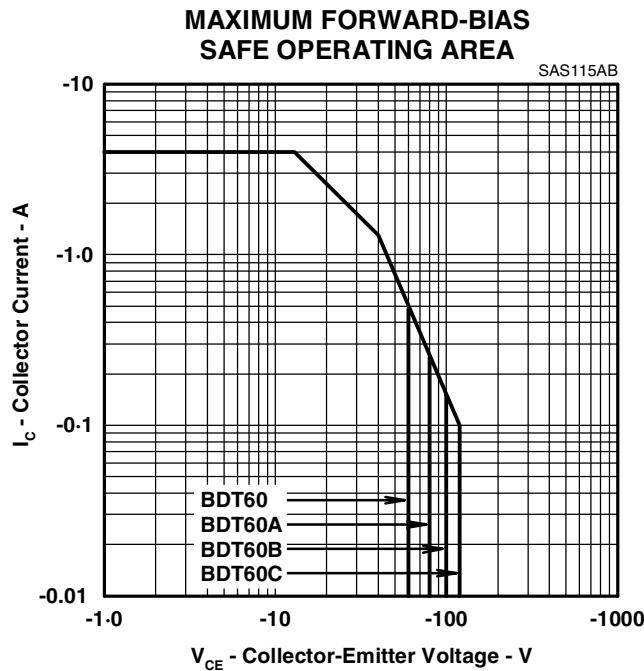


Figure 4.

### THERMAL INFORMATION

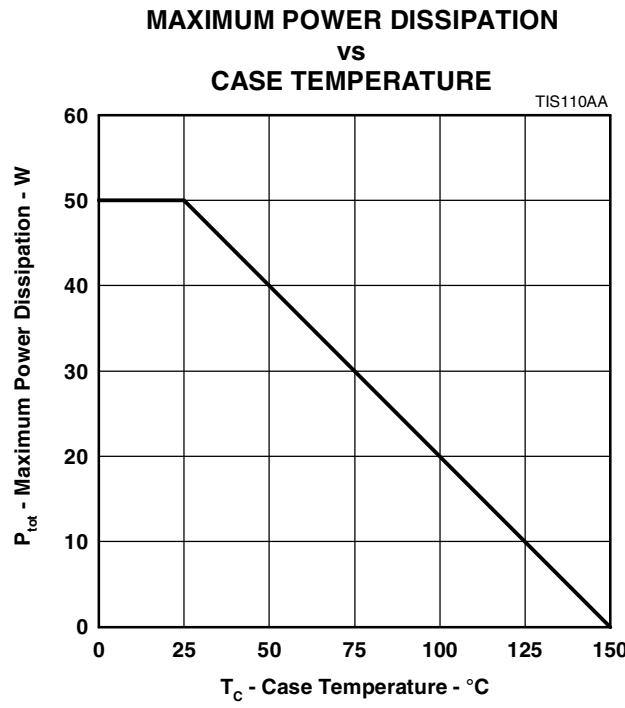


Figure 5.

### PRODUCT INFORMATION

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